Excellent Integrated System Limited

Stocking Distributor

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TT Electronics/Optek Technology OP509A

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of TT Electronics/Optek Technology: Excellent Integrated System Limited

Datasheet of OP509A - PHOTOTRANS SILICON NPN SIDE LOOK

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

NPN Silicon Phototransistor

OP508F, OP509, OP538F Series



Features:

- Flat lensed for wide acceptance angle (OP508F)
- Lensed for high sensitivity (OP509)
- Easily stackable on 0.100" (2.54 mm) hole centers
- Inexpensive plastic package
- Mechanically and spectrally matched to OP168 and OP268 series of infrared emitting diodes



Description:

Each device in the **OP508F** series consists of a NPN silicon phototransistor mounted in a flat, black plastic "end-looking" package. The flat sensing surface allows an acceptance half-angle of 60° when measured from the optical axis to the half power point.

Each device in the **OP509** series consists of a NPN silicon phototransistor mounted in a lensed, clear plastic "end-looking" package. The lensing effect of the package allows an acceptance half-angle of 25° when measured from the optical axis to the half power point.

Each device in the **OP538F** series consists of a NPN silicon photodarlington mounted in a flat, black plastic "end-looking" package. The flat sensing surface allows an acceptance half-angle of 65° when measured from the optical axis to the half power point.

OP508F, OP509 and **OP538F** series devices can be mounted on 0.100" (2.54 mm) hole centers, which makes them an ideal low-cost alternate to hermetic OP600 sensors. **OP508F, OP509** and **OP538F** series devices are mechanically and spectrally matched to the OP168F and OP268F series of infrared emitting diodes.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

For custom versions of the **OP508F, OP509** and **OP538F** series devices please contact your OPTEK representative.

Applications:

- Applications requiring a wide acceptance angle
- · Applications requiring high sensitivity
- Space-limited applications

Ordering Information						
Part Number	Sensor	Viewing Angle	Lead Length			
OP508FA						
OP508FB		120°				
OP508FC	Phototransistor					
OP509A	PHOLOLIANSISLOI					
ОР509В		50°	0.50"			
OP509C						
OP538FA						
OP538FB	Photodarlington	120°				
OP538FC						



General Note

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Datasheet of OP509A - PHOTOTRANS SILICON NPN SIDE LOOK

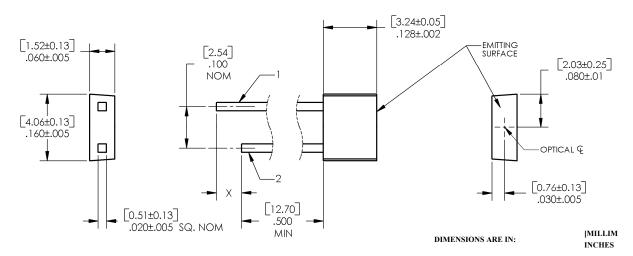
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NPN Silicon Phototransistor

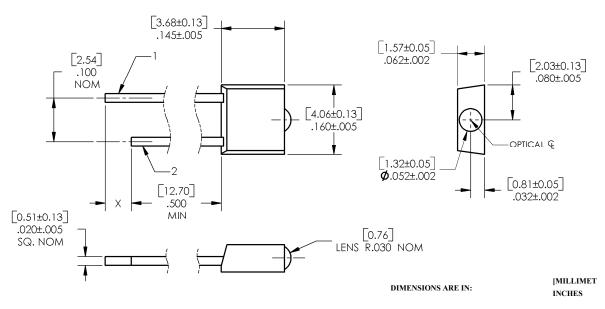
OP508F, OP509, OP538F Series



OP508F, OP538F (A, B, C)



OP509 (A, B, C)





Pin#	Transistor	
1	Collector	
2	Emitter	

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NPN Silicon Phototransistor

OP508F, OP509, OP538F Series



Electrical Specifications

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)		
Storage and Operating Temperature Range	-40° C to +100° C	
Collector-Emitter Voltage	30 V	
Emitter-Collector Voltage	5 V	
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽¹⁾	
Power Dissipation	100 mW ⁽²⁾	

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
	On-State Collector Current			20.00			
	OP509A (Dome Lens)	5.70	-	20.00		$V_{CE} = 5.0 \text{ V}, E_E = 5 \text{ mW/cm}^{2(3)}$	
I _{C(ON)}	OP508FA (Flat Lens)	2.70	-	10.00			
	OP509B (Dome Lens)	1.40	-	10.60	mA		
	OP509C (Dome Lens)	0.70	-	5.10	IIIA	V _{CE} - 3.0 V, E _E - 3 IIIVV/CIII	
	OP508FB (Flat Lens)	0.65	-	3.10			
	OP508FC (Flat Lens)	0.34	-				
	OP538A (Flat Lens)	6.80	-	-			
	OP538B (Flat Lens)	2.30	-	20.50	mA	$V_{CE} = 5.0 \text{ V}, E_E = 0.5 \text{ mW/cm}^{2(3)}$	
	OP538C (Flat Lens)	1.10	-	-			
I _C /Δ T	Relative I _C Charge with Temperature	-	1.00	-	%/°C	$V_{CE} = 5 \text{ V.0, } E_E = 1.0 \text{ mW/cm}^{2(3)}, \lambda = 890 \text{ nm}$	
I _{CEO}	Collector-Dark Current						
	OP508F & OP509	_	-	100		$V_{CE} = 10.0 \text{ V, } E_E = 0^{(4)}$	
	OP538F	-	-	225	nA		
	Collector-Emitter Breakdown Voltage						
V _{(BR)CEO}	OP508F & OP509	30	_	_			
	OP538F	15	-	-	V	$I_C = 1.00 \text{ mA}, E_E = 0$	
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5	-	-	V	Ι _Ε = 100 μΑ	
V _{CE(SAT)}	Collector-Emitter Saturation Voltage						
	OP508F	-	-	0.4	V	$I_C = 300 \mu A, E_E = 5 \text{mW/cm}^{2 (3)}$	
	OP509	-	-	0.4	V	$I_C = 250 \mu\text{A}, E_E = 5 \text{mW/cm}^{2(3)}$	
	OP538F	_	_	1.0		$I_C = 100 \mu A, E_E = 5 \text{mW/cm}^{2(3)}$	

Notes:

- 1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum 20 grams force may be applied to the leads when soldering.
- 2. Derate linearly 1.33 mW/° C above 25° C.
- 3. Light source is an unfiltered GaAs or GaAlAs LED with a peak emission wavelength of 935 or 890 nm and a radiometric intensity level which varies less than 10% over the entire lens surface of the phototransistor being tested.

 4. To calculate typical collector dark current in μA , use the formula $I_{CEO}=10^{(0.040\,T_A^{-3.4})}$, where T_A is ambient temperature in °C.

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NPN Silicon Phototransistor

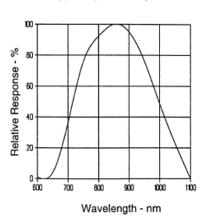
OP508F, OP509, OP538F Series

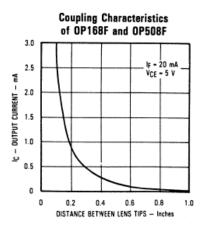


Performance

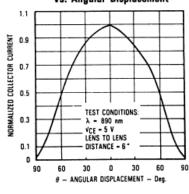
OP508FA, OP508FB, OP508FC, OP508FD



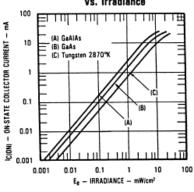




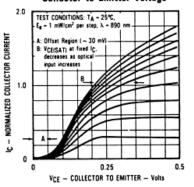
Normalized Collector Current vs. Angular Displacement



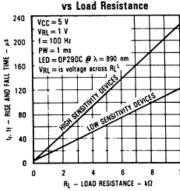
On-State Collector Current vs. Irradiance



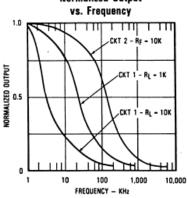
Normalized Collector Current vs. Collector to Emitter Voltage



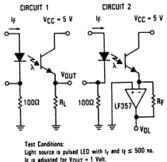
Rise and Fall Time



Normalized Output



Switching Time **Test Circuit**



source is pulsed LED w adjusted for VOUT = 1

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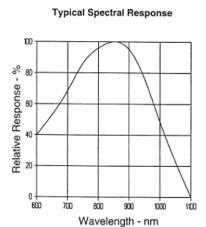
NPN Silicon Phototransistor

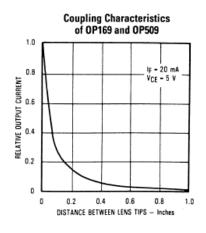
OP508F, OP509, OP538F Series

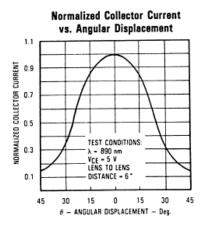


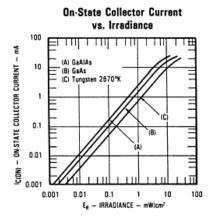
Performance

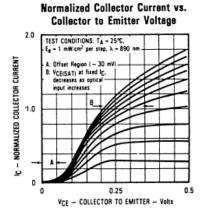
OP509A, OP509B, OP509C, OP509D

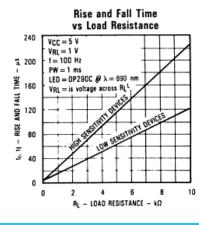


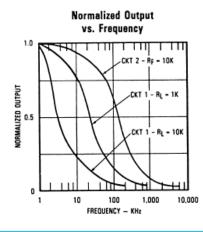


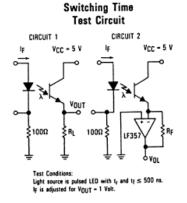












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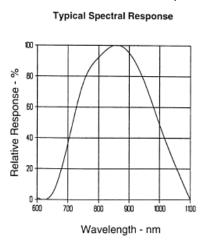
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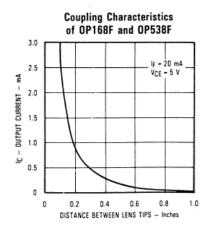
OP508F, OP509, OP538F Series

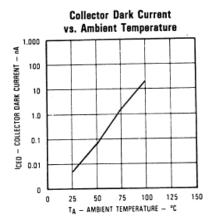


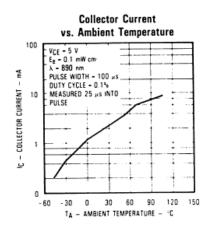
Performance

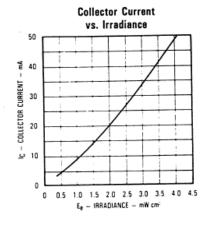
OP538FA, OP538FB, OP538FC,

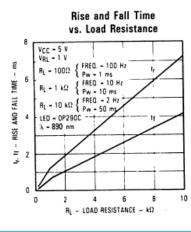


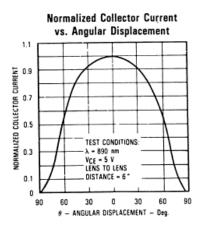


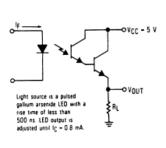












Switching Time

Test Circuit

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